**Typical Applications**
The HMC1019ALP4E is ideal for:
- Fiber Optics & Broadband Telecom
- Microwave Radio & VSAT
- Military Radios, Radar & ECM
- Space Applications
- Sensors
- Test & Measurement Equipment

**Features**
- 0.5 dB LSB Steps to 15.5 dB
- TTL/CMOS Compatible, Serial Control
- Unique Asynchronous Mode Control Allows Immediate Attenuation Level Setting
- ±0.5 dB Typical Bit Error
- High Input IP3: +45 dBm
- 24 Lead 4x4mm SMT Package: 16mm2

**General Description**
The HMC1019ALP4E is a broadband 5-bit GaAs IC digital attenuator in a low cost leadless surface mount package. Covering 0.1 to 30.0 GHz, the insertion loss is less than 4.0 dB typical. The attenuator bit values are 0.5 (LSB), 1, 2, 4, 8 for a total attenuation of 15.5 dB. Attenuation accuracy is excellent at ±0.3 dB typical step error with an IIP3 of +45 dBm. The control interface is CMOS/TTL compatible and accepts a three wire serial input. The HMC1019ALP4E features a user selectable power up state and a serial output port for cascading other Analog Devices serial controlled components.

**Electrical Specifications, \( T_A = +25^\circ \text{C} \), With Vdd = Vdd1 = +5V, Vss = -5V**

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Frequency (GHz)</th>
<th>Min.</th>
<th>Typ.</th>
<th>Max.</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>Insertion Loss</td>
<td>0.1 - 18.0 GHz</td>
<td>3.5</td>
<td>4.5</td>
<td>6.0</td>
<td>dB</td>
</tr>
<tr>
<td></td>
<td>18.0 - 26.5 GHz</td>
<td>4.5</td>
<td></td>
<td>6.5</td>
<td>dB</td>
</tr>
<tr>
<td></td>
<td>26.5 - 30.0 GHz</td>
<td>5.0</td>
<td></td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td>Attenuation Range</td>
<td>0.1 - 30.0 GHz</td>
<td>15.5</td>
<td></td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td>Return Loss (RF1 &amp; RF2, All Atten. States)</td>
<td>0.1 - 30.0 GHz</td>
<td>12</td>
<td></td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td>Attenuation Accuracy: (Referenced to Insertion Loss)</td>
<td>0.1 - 30.0 GHz</td>
<td>± (0.3 + 6%) of Atten. Setting Max</td>
<td></td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td></td>
<td>0.1 - 30.0 GHz</td>
<td>± (0.3 + 8%) of Atten. Setting Max</td>
<td></td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td>Input Power for 0.1 dB Compression</td>
<td>0.1 - 0.5 GHz</td>
<td>22</td>
<td>25</td>
<td></td>
<td>dBm</td>
</tr>
<tr>
<td></td>
<td>0.5 - 30.0 GHz</td>
<td>28</td>
<td></td>
<td></td>
<td>dBm</td>
</tr>
<tr>
<td>Input Third Order Intercept Point</td>
<td>0.1 - 0.5 GHz</td>
<td>32</td>
<td>42</td>
<td></td>
<td>dBm</td>
</tr>
<tr>
<td>(Two-Tone Input Power= 0 dBm Each Tone)</td>
<td>0.5 - 30.0 GHz</td>
<td>42</td>
<td>45</td>
<td></td>
<td>dBm</td>
</tr>
<tr>
<td>Switching Characteristics</td>
<td>tRISE, tFALL (10/90% RF)</td>
<td>60</td>
<td>90</td>
<td>60</td>
<td>ns</td>
</tr>
<tr>
<td></td>
<td>ION/TOFF (50% CTL to 10/90% RF)</td>
<td>80</td>
<td>90</td>
<td>80</td>
<td>ns</td>
</tr>
<tr>
<td>Idd1</td>
<td>0.1 - 30.0 GHz</td>
<td>2.5</td>
<td>4.5</td>
<td>6.5</td>
<td>mA</td>
</tr>
<tr>
<td>Iss</td>
<td>0.1 - 30.0 GHz</td>
<td>-7.0</td>
<td>-5.5</td>
<td>-3.0</td>
<td>mA</td>
</tr>
</tbody>
</table>

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COMPARABLE PARTS
View a parametric search of comparable parts.

EVALUATION KITS
• HMC1019A Evaluation Board

DOCUMENTATION
Data Sheet
• HMC1019ALP4E: 0.5 dB LSB GaAs MMIC 5-Bit Digital Attenuator, 0.1 - 30 GHz Preliminary Data Sheet

TOOLS AND SIMULATIONS
• HMC1019ALP4E S-Parameters

REFERENCE MATERIALS
Product Selection Guide
• RF, Microwave, and Millimeter Wave IC Selection Guide 2017

DESIGN RESOURCES
• HMC1019A Material Declaration
• PCN-PDN Information
• Quality And Reliability
• Symbols and Footprints

DISCUSSIONS
View all HMC1019A EngineerZone Discussions.

SAMPLE AND BUY
Visit the product page to see pricing options.

TECHNICAL SUPPORT
Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK
Submit feedback for this data sheet.
HMC1019ALP4E

0.5 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 30 GHz

**Insertion Loss vs. Temperature**

(Only Major States are Shown)

**Normalized Attenuation**

(Only Major States are Shown)

**Input Return Loss**

(Only Major States are Shown)

**Output Return Loss**

(Only Major States are Shown)

**Bit Error vs. Attenuation State**

(Only Major States are Shown)

**Bit Error vs. Frequency**

(Only Major States are Shown)
HMC1019ALP4E
0.5 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 30 GHz

Relative Phase vs. Frequency
(Only Major States are Shown)

Step Attenuation vs. Attenuation State
0.1 - 18 GHz

Input Power for 0.1 dB Compression

Input IP3 Over Major Attenuation States

Input IP3 vs. Temperature
(Minimum Attenuation State)
Serial Control Interface

The HMC1019ALP4E contains a 3-wire SPI compatible digital interface (SERIN, CLK, LE). The serial control interface is activated when S/A is kept high. The 5-bit serial word must be loaded MSB first as a 6-bit word with the first bit ignored. The positive-edge sensitive CLK and LE requires clean transitions. If mechanical switches are used, sufficient debouncing should be provided. When LE is high, 5-bit data in the serial input register is transferred to the attenuator. When LE is high CLK is masked to prevent data transition during output loading.

For all modes of operations, the state will stay constant while LE is kept low.

Serial Mode Truth Table

<table>
<thead>
<tr>
<th>Control Voltage Input</th>
<th>Attenuation State RF1 - RF2</th>
</tr>
</thead>
<tbody>
<tr>
<td>P4 8 dB</td>
<td></td>
</tr>
<tr>
<td>High</td>
<td>High</td>
</tr>
<tr>
<td>P3 4 dB</td>
<td>High</td>
</tr>
<tr>
<td>High</td>
<td>High</td>
</tr>
<tr>
<td>P2 2 dB</td>
<td>Low</td>
</tr>
<tr>
<td>High</td>
<td>Low</td>
</tr>
<tr>
<td>P1 1 dB</td>
<td>High</td>
</tr>
<tr>
<td>High</td>
<td>Low</td>
</tr>
<tr>
<td>P0 0.5 dB</td>
<td>High</td>
</tr>
<tr>
<td>High</td>
<td>Low</td>
</tr>
</tbody>
</table>

Any combination of the above states will provide an attenuation approximately equal to the sum of the bits selected.

Asynchronous Mode

The HMC1019ALP4E can be switched to an asynchronous mode to change the attenuation state rapidly to one of four predefined states. The logic state of ASM1-ASM2 determines one of the four attenuation states in the asynchronous mode per truth table. The asynchronous mode works either directly or latched. To activate the direct-asynchronous-mode, S/A needs to be at logic low and LE needs to be at logic high. In the direct-asynchronous-mode, any change in the logic state of ASM1-ASM2 directly affects the attenuation state. In the latched-asynchronous-mode, the attenuation state changes per the asynchronous mode truth table when S/A is at logic low and LE is pulsed per the timing diagram. The attenuation stays constant (latched) as long as LE stays low. In the asynchronous mode, the inputs SERIN and CLK do not affect the attenuation state.
**Timing Diagram (Latched Asynchronous Mode)**

**Power-Up States**

If LE is set to logic LOW at power-up, the logic state of PUP determines the power-up state of the part per PUP truth table. If the LE is set to logic HIGH at power-up, the logic state of ASM1-ASM2 determines the power-up state of the part per truth table for the asynchronous mode. The attenuator latches in the desired power-up state approximately 200 ms after power-up.

### Bias Voltages & Currents

<table>
<thead>
<tr>
<th>Voltage</th>
<th>Bias</th>
<th>Current</th>
</tr>
</thead>
<tbody>
<tr>
<td>Vdd</td>
<td>+5V</td>
<td>0.06 mA</td>
</tr>
<tr>
<td>Vdd1</td>
<td>+5V</td>
<td>4.5 mA</td>
</tr>
<tr>
<td>Vss</td>
<td>-5V</td>
<td>5.5 mA</td>
</tr>
</tbody>
</table>

### Control Voltage

<table>
<thead>
<tr>
<th>State</th>
<th>Condition</th>
</tr>
</thead>
<tbody>
<tr>
<td>Low</td>
<td>0 to 0.8V @ 1 µA</td>
</tr>
<tr>
<td>High</td>
<td>2 to 5V @ 1 µA</td>
</tr>
</tbody>
</table>

### Asynchronous Mode Truth Table

<table>
<thead>
<tr>
<th>ASM1</th>
<th>ASM2</th>
<th>Attenuation State RF1-RF2</th>
</tr>
</thead>
<tbody>
<tr>
<td>High</td>
<td>High</td>
<td>Reference I.L.</td>
</tr>
<tr>
<td>High</td>
<td>Low</td>
<td>1.5 dB</td>
</tr>
<tr>
<td>Low</td>
<td>High</td>
<td>14 dB</td>
</tr>
<tr>
<td>Low</td>
<td>Low</td>
<td>15.5 dB</td>
</tr>
</tbody>
</table>

### PUP Truth Table

<table>
<thead>
<tr>
<th>PUP</th>
<th>Attenuation State</th>
</tr>
</thead>
<tbody>
<tr>
<td>High</td>
<td>Reference I.L.</td>
</tr>
<tr>
<td>Low</td>
<td>15.5 dB</td>
</tr>
</tbody>
</table>

Note: The logic state of ASM1-ASM2 determines the power-up state of the part per truth table for the asynchronous mode when LE is high at power-up.
**Absolute Maximum Ratings**

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Specification</th>
</tr>
</thead>
<tbody>
<tr>
<td>RF Input Power (0.1 to 30.0 GHz)</td>
<td>+27 dBm</td>
</tr>
<tr>
<td>Control Voltage (CLK, SERIN, LE, PUP, ASM1, ASM2, S/A)</td>
<td>Vdd + 0.5V</td>
</tr>
<tr>
<td>Vdd, Vdd1</td>
<td>+7 Vdc</td>
</tr>
<tr>
<td>Vss</td>
<td>-7 Vdc</td>
</tr>
<tr>
<td>Channel Temperature</td>
<td>150 °C</td>
</tr>
<tr>
<td>Continuous Pdiss (T = 85 °C)</td>
<td>0.453 W</td>
</tr>
<tr>
<td>(derate 6.8 mW/°C above 85 °C)</td>
<td></td>
</tr>
<tr>
<td>Thermal Resistance</td>
<td>143.5 °C/W</td>
</tr>
<tr>
<td>Storage Temperature</td>
<td>-65 to + 150 °C</td>
</tr>
<tr>
<td>Operating Temperature</td>
<td>-40 to +85 °C</td>
</tr>
<tr>
<td>ESD Sensitivity (HBM)</td>
<td>Class 1A</td>
</tr>
</tbody>
</table>

**Outline Drawing**

**Package Information**

<table>
<thead>
<tr>
<th>Part Number</th>
<th>Package Body Material</th>
<th>Lead Finish</th>
<th>MSL Rating</th>
<th>Package Marking</th>
</tr>
</thead>
<tbody>
<tr>
<td>HMC1019ALP4E</td>
<td>RoHS-compliant Low Stress Injection Molded Plastic</td>
<td>100% matte Sn</td>
<td>MSL3 [1]</td>
<td>1019A XXXX</td>
</tr>
</tbody>
</table>

[1] Max peak reflow temperature of 260 °C
[2] 4-Digit lot number XXXX

**Electrostatic Sensitive Device**

**Observe Handling Precautions**

**Notes:**
1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
   PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.
**Pin Descriptions**

<table>
<thead>
<tr>
<th>Pad Number</th>
<th>Function</th>
<th>Description</th>
<th>Interface Schematic</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>SERIN</td>
<td>See truth table, control voltage table and timing diagram.</td>
<td></td>
</tr>
<tr>
<td>2</td>
<td>LE</td>
<td></td>
<td></td>
</tr>
<tr>
<td>3</td>
<td>Vss</td>
<td>Negative Bias -5V</td>
<td></td>
</tr>
<tr>
<td>4, 15</td>
<td>GND</td>
<td>These pins and package bottom must be connected to RF/DC ground.</td>
<td></td>
</tr>
<tr>
<td>6-13, 16</td>
<td>N/C</td>
<td>The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.</td>
<td></td>
</tr>
<tr>
<td>5, 14</td>
<td>RF1, RF2</td>
<td>These pins are DC coupled and matched to 50 Ohm. Blocking capacitors are required if RF line potential is not equal to 0V.</td>
<td></td>
</tr>
<tr>
<td>17</td>
<td>Vdd1</td>
<td>Positive Bias +5V</td>
<td></td>
</tr>
<tr>
<td>18</td>
<td>SEROUT</td>
<td>Serial input data delayed by 6 clock cycles.</td>
<td></td>
</tr>
<tr>
<td>19</td>
<td>PUP</td>
<td>See truth table, control voltage table and timing diagram.</td>
<td></td>
</tr>
<tr>
<td>21</td>
<td>ASM1</td>
<td></td>
<td></td>
</tr>
<tr>
<td>22</td>
<td>ASM2</td>
<td></td>
<td></td>
</tr>
<tr>
<td>23</td>
<td>S/A</td>
<td></td>
<td></td>
</tr>
<tr>
<td>24</td>
<td>CLK</td>
<td></td>
<td></td>
</tr>
<tr>
<td>20</td>
<td>Vdd</td>
<td>Serial Controller Bias +5V</td>
<td></td>
</tr>
</tbody>
</table>
Application Circuit

HMC1019ALP4E

0.5 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 30 GHz
**HMC1019ALP4E**

0.5 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 30 GHz

### Evaluation PCB

![Evaluation PCB Diagram]

**List of Materials for Evaluation PCB EV1HMC1019ALP4**

<table>
<thead>
<tr>
<th>Item</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>J1, J2</td>
<td>2.9 mm PC Mount RF Connector</td>
</tr>
<tr>
<td>J3, J4, J6</td>
<td>DC Connector</td>
</tr>
<tr>
<td>J5</td>
<td>2mm DC Header</td>
</tr>
<tr>
<td>C1-C3</td>
<td>100 pF Capacitor, 0402 Pkg.</td>
</tr>
<tr>
<td>C4-C6</td>
<td>1000 pF Capacitor, 0402 Pkg.</td>
</tr>
<tr>
<td>U1</td>
<td>HMC1019ALP4E Digital Attenuator</td>
</tr>
<tr>
<td>PCB [2]</td>
<td>600-00196-00-2 Evaluation Board</td>
</tr>
</tbody>
</table>

[1] Reference this number when ordering complete evaluation PCB


The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Analog Devices upon request.
HMC1019ALP4E

0.5 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 30 GHz

Notes: